INTEGRATED CIRCUITS

DATA SHEET

74F51

Dual 2-wide 2-input, 2-wise 3-input AND-OR-invert gate

Product specification

1989 Mar 03

IC15 Data Handbook





Dual 2-wide 2-input, 2-wide 3-input AND-OR-invert gate

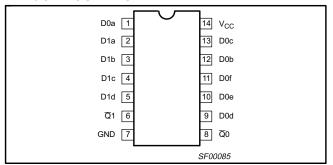
74F51

TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)
74F51	3.0ns	3.5mA

ORDERING INFORMATION

DESCRIPTION	COMMERCIAL RANGE V_{CC} = 5V ±10%, T_{amb} = 0°C to +70°C	PKG DWG#		
14-pin plastic DIP	N74F51N	SOT27-1		
14-pin plastic SO	N74F51D	SOT108-1		

PIN CONFIGURATION

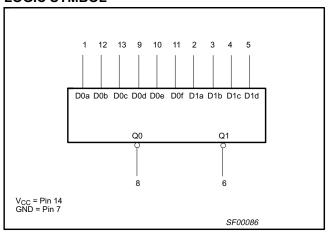


INPUT AND OUTPUT LOADING AND FAN-OUT TABLE

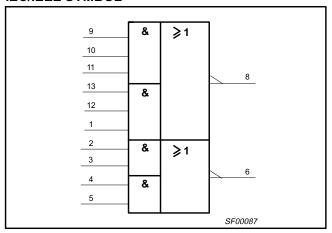
PINS	DESCRIPTION	74F (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW		
Dna, Dnb, Dnc, Dnd, Dne, Dnf	Data inputs	1.0/1.0	20μA/0.6mA		
<u>Q</u> 0, <u>Q</u> 1	Data outputs	50/33	1.0mA/20mA		

NOTE: One (1.0) FAST unit load is defined as: 20μA in the High state and 0.6mA in the Low state.

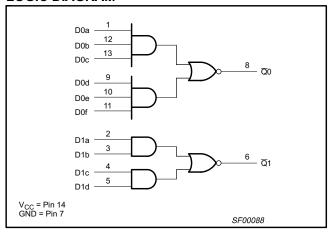
LOGIC SYMBOL



IEC/IEEE SYMBOL



LOGIC DIAGRAM



FUNCTION TABLE FOR 3-INPUT GATES

		INP	UTS			OUTPUT					
D0a	D0b	<u>Q</u> 0									
Н	Н	Н	Х	Х	Х	L					
Х	Х	Х	Н	Н	Н	L					
	All other combinations										
NOTEO.											

NOTES:

H = High voltage level

L = Low voltage level

X = Don't care

FUNCTION TABLE FOR 2-INPUT GATES

	INP	UTS		OUTPUT
D1a	D1b	<u>Q</u> 1		
Н	Н	Х	Х	L
Х	Х	L		
	All other co	mbinations		Н

NOTES:

H = High voltage level

L = Low voltage level

X = Don't care

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ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limits set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free-air temperature range.)

SYMBOL	PARAMETER	RATING	UNIT
V _{CC}	Supply voltage	-0.5 to +7.0	V
V _{IN}	Input voltage	-0.5 to +7.0	V
I _{IN}	Input current	-30 to +5	mA
V _{OUT}	Voltage applied to output in High output state	-0.5 to V_{CC}	V
l _{OUT}	Current applied to output in Low output state	40	mA
T _{amb}	Operating free-air temperature range	0 to +70	°C
T _{stg}	Storage temperature range	-65 to +150	°C

RECOMMENDED OPERATING CONDITIONS

CYMDOL	DADAMETED		LIMITS						
SYMBOL	PARAMETER	MIN	NOM	MAX	UNIT				
V_{CC}	Supply voltage	4.5	5.0	5.5	V				
V_{IH}	High-level input voltage	2.0			V				
V _{IL}	Low-level input voltage			0.8	V				
I _{IK}	Input clamp current			-18	mA				
I _{OH}	High-level output current			-1	mA				
I _{OL}	Low-level output current			20	mA				
T _{amb}	Operating free-air temperature range	0		+70	°C				

DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

OVMDOL	DADAMETED	TEST COMPLETE	NO1		LIMITS		UNIT	
SYMBOL	PARAMETER	TEST CONDITIO	NO.	MIN	TYP ²	MAX] "	
V	Lligh lovel output voltage	V _{CC} = MIN, V _{IL} = MAX	±10%V _{CC}	2.5			V	
V _{OH}	High-level output voltage	V _{IH} = MIN, I _{OH} = MAX	±5%V _{CC}	2.7	3.4		V	
· · ·	Low lovel output voltage	$V_{CC} = MIN, V_{IL} = MAX$	±10%V _{CC}		0.30	0.50	V	
V _{OL}	Low-level output voltage	$V_{IH} = MIN, I_{OL} = MAX$	±5%V _{CC}		0.30	0.50	V	
V_{IK}	Input clamp voltage	$V_{CC} = MIN, I_I = I_{IK}$		-0.73	-1.2	V		
I _I	Input current at maximum input voltage	$V_{CC} = MAX, V_I = 7.0V$			100	μΑ		
I _{IH}	High-level input current	$V_{CC} = MAX, V_I = 2.7V$			20	μΑ		
I _{IL}	Low-level input current	$V_{CC} = MAX, V_I = 0.5V$			-0.6	mA		
Ios	Short-circuit output current ³	V _{CC} = MAX	V _{CC} = MAX			-150	mA	
	Supply surrent (total)	\/ - MAY	V _{IN} = GND		1.8	3.0	mA	
Icc	Supply current (total)	V _{CC} = MAX	V _{IN} = 4.5V		5.5	7.5	mA	

NOTES:

1. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.

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All typical values are at V_{CC} = 5V, T_{amb} = 25°C.
Not more than one output should be shorted at a time. For testing I_{OS}, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a High output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

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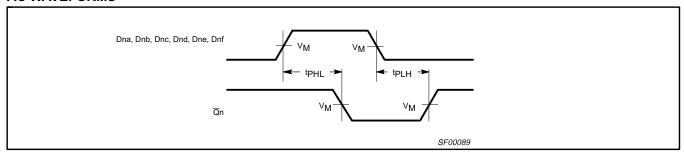
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AC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITION	T,	/ _{CC} = +5.0 _{amb} = +25° 50pF, R _L =	C	V _{CC} = +5. T _{amb} = 0°C C _L = 50pF,	UNIT	
			MIN	TYP	MAX	MIN	MAX	
t _{PLH} t _{PHL}	Propagation delay Dna, Dnb, Dnc, Dnd, Dne, Dnf to Qn	Waveform 1	2.0 1.0	3.5 2.5	5.5 4.0	1.5 1.0	6.5 4.5	ns

AC WAVEFORMS

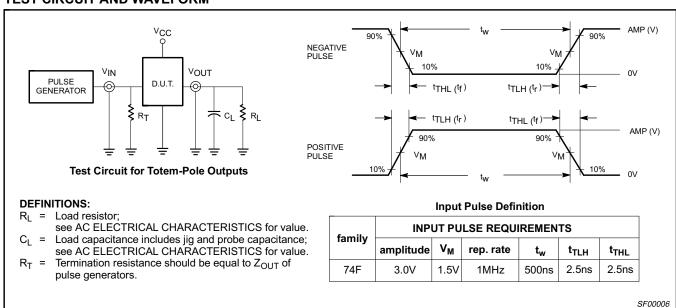


Waveform 1. Propagation Delay for Inverting Outputs

NOTE:

For all waveforms, $V_M = 1.5V$.

TEST CIRCUIT AND WAVEFORM



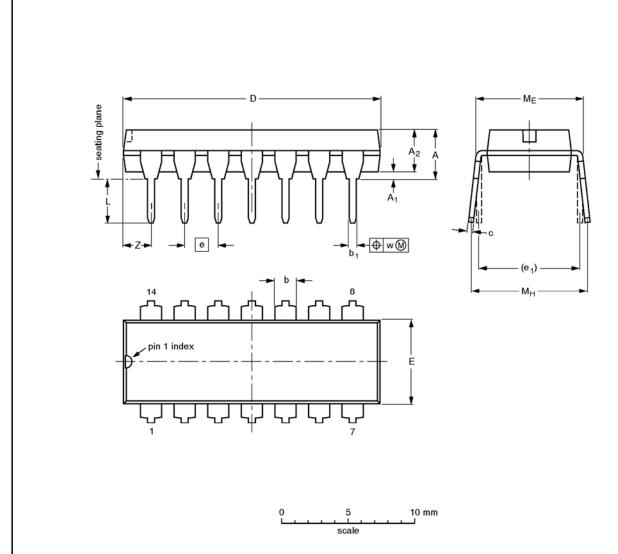
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DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E (1)	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	PROJECTION	ISSUE DATE			
SOT27-1	050G04	MO-001AA				92-11-17 95-03-11	

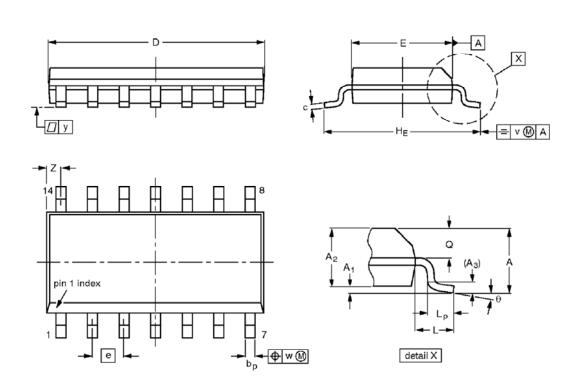
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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



scale

DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	А3	bр	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z (1)	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075		0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

5 mm

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT108-1	076E06S	MS-012AB				95-01-23 97-05-22

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Data sheet status

Data sheet status	Product status	Definition [1]	
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.	
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.	
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product	

^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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